



DMT6007LFGQ

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C
001/	6mΩ @ V _{GS} = 10V	80A
60V	8.5mΩ @ V _{GS} = 4.5V	70A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Brushless DC motor controls
- DC-DC converters
- Load switches

N-CHANNEL ENHANCEMENT MODE MOSFET

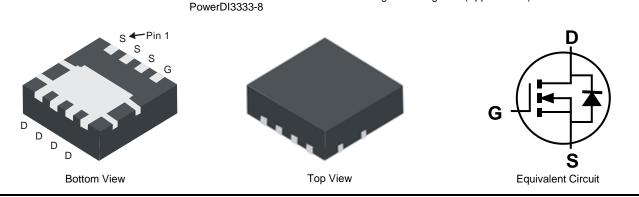
Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Excellent Q_{gd} × R_{DS(ON)} Product (FOM)
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- 100% Unclamped Inductive Switching, Test in Production Ensures More Reliable and Robust End Application
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMT6007LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

Part Number	Deckore	Packing		
Part Number	Package	Qty.	Carrier	
DMT6007LFGQ-7	PowerDI3333-8	2,000	Tape & Reel	
DMT6007LFGQ-13	PowerDI3333-8	3,000	Tape & Reel	

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

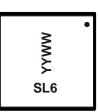
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



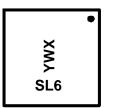
Marking Information

Site1:



SL6 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

Site2:



SL6 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023) W = Week (ex: a = Week 27, z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	60	V	
Gate-Source Voltage		Vgss	±20	V
	T _A = +25°C T _A = +70°C	۱ _D	15 12	А
Continuous Drain Current (Note 5) VGS = 10V	Tc = +25°C Tc = +70°C	٥l	80 65	А
Maximum Continuous Body Diode Forward Current (Note	ls	80	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	80	А	
Avalanche Current, L = 0.1mH	I _{AS}	20	A	
Avalanche Energy, L = 0.1mH	Eas	20	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5) T _A = +25°C		PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	55	°C/W	
Total Power Dissipation (Note 6) $T_{C} = +25^{\circ}C$		PD	62.5	W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. R_{0JA} is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. R_{0JC} is guaranteed by design while R_{0JA} is determined by the user's board design.

6. Short duration pulse test used to minimize self-heating effect.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

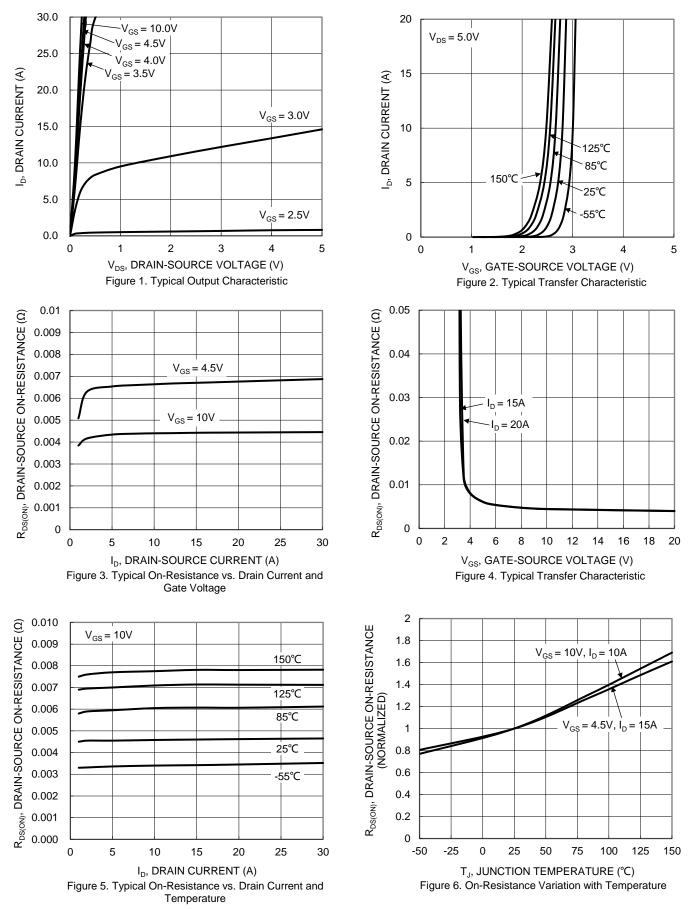
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			1	r			
Drain-Source Breakdown Voltage	BVDSS	60		—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	—	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	0.8	—	2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Descent	_	4.5	6	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source Off-Resistance	Rds(on)	_	6.5	8.5	11122	V _{GS} = 4.5V, I _D = 15A	
Forward Transconductance	GFS	_	100	—	S	V _{DS} = 5V, I _D = 20A	
Diode Forward Voltage	Vsd	_	0.9	1.2	V	VGS = 0V, IS = 20A	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	Ciss	—	2090	—		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	746	—	pF		
Reverse Transfer Capacitance	Crss	_	38.5	_			
Gate Resistance	Rg	_	0.59	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	19.3	—			
Total Gate Charge (V _{GS} = 10V)	Qg	_	41.3	—		V _{DS} = 30V, I _D = 20A	
Gate-Source Charge	Qgs	_	6.0	_	nC		
Gate-Drain Charge	Q _{gd}	_	8.8	—	1		
Turn-On Delay Time	t _{D(ON)}	_	5.7	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 20A, R_G = 3\Omega$	
Turn-On Rise Time	tR		4.3				
Turn-Off Delay Time	tD(OFF)		23.4		ns		
Turn-Off Fall Time	tF	_	9.7	—	1		
Body Diode Reverse Recovery Time	trr	_	35.4	—	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	38.2	_	nC	IF = 20A, di/dt = 100A/µs	

Notes: 7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

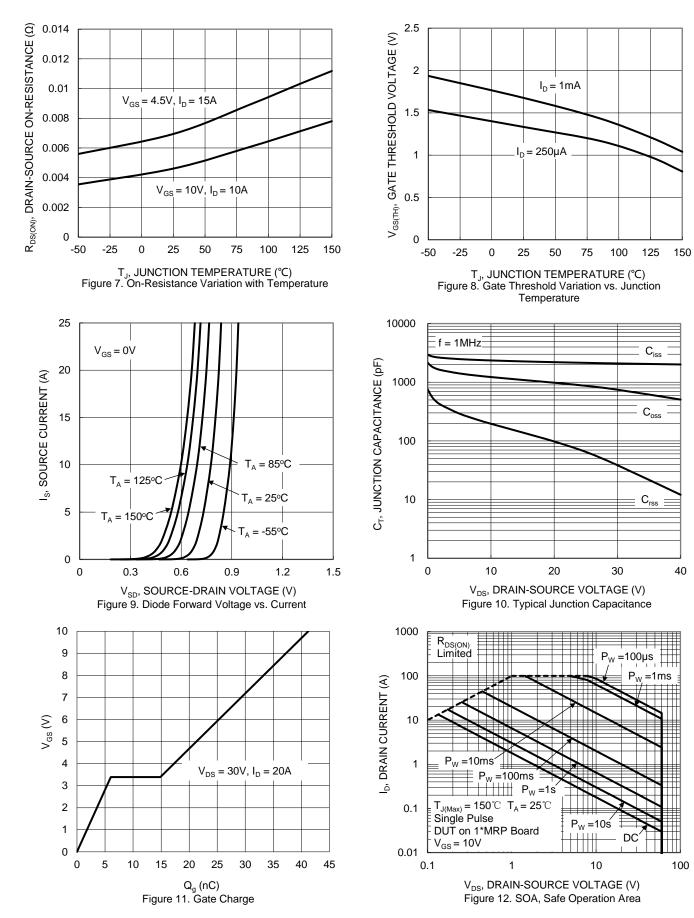


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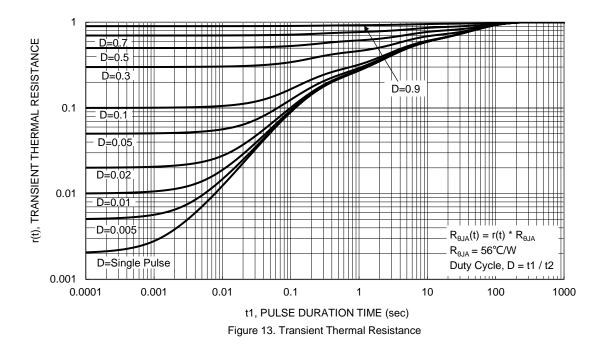
DMT6007LFGQ Document number: DS40969 Rev. 3 - 2





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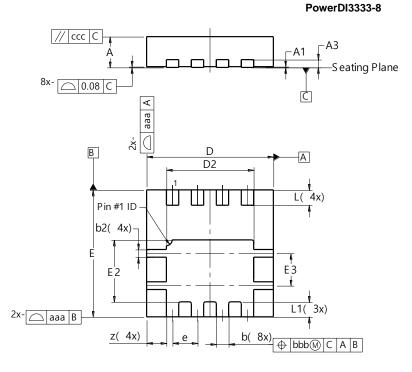






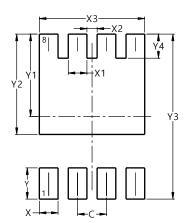
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
e	-	-	0.65		
L	0.35	0.45	0.40		
L1	0.3				
z	0.515				
aaa	0.25				
bbb	0.10				
CCC	0.10				
All Dimensions in mm					

Suggested Pad Layout



PowerDI3333-8

Dimensions Value (in mm) C 0.650 X 0.420 X1 0.420 X2 0.230 X3 2.370 Y 0.700 Y1 1.850 Y2 2.250		
X 0.420 X1 0.420 X2 0.230 X3 2.370 Y 0.700 Y1 1.850	Dimensions	Value (in mm)
X1 0.420 X2 0.230 X3 2.370 Y 0.700 Y1 1.850	С	0.650
X2 0.230 X3 2.370 Y 0.700 Y1 1.850	Х	0.420
X3 2.370 Y 0.700 Y1 1.850	X1	0.420
Y 0.700 Y1 1.850	X2	0.230
Y1 1.850	X3	2.370
	Y	0.700
Y2 2.250	Y1	1.850
	Y2	2.250
Y3 3.700	Y3	3.700
Y4 0.540	Y4	0.540

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